8-Bit Serial or Parallel-Input/Serial-Output Shift Register with 3-State Output

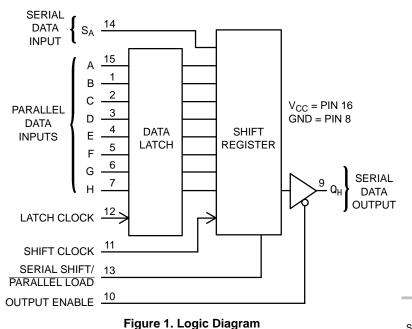
High–Performance Silicon–Gate CMOS

The MC74HC589A device consists of an 8–bit storage latch which feeds parallel data to an 8–bit shift register. Data can also be loaded serially (see the Function Table). The shift register output, Q_H , is a 3–state output, allowing this device to be used in bus–oriented systems.

The HC589A directly interfaces with the SPI serial data port on CMOS MPUs and MCUs.

Features

- Output Drive Capability: 15 LSTTL Loads
- Outputs Directly Interface to CMOS, NMOS, and TTL
- Operating Voltage Range: 2.0 to 6.0 V
- Low Input Current: 1 µA
- High Noise Immunity Characteristic of CMOS Devices
- In Compliance with the Requirements Defined by JEDEC Standard No. 7 A
- Chip Complexity: 526 FETs or 131.5 Equivalent Gates
- NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q100 Qualified and PPAP Capable
- These Devices are Pb-Free, Halogen Free and are RoHS Compliant



ON

ON Semiconductor®

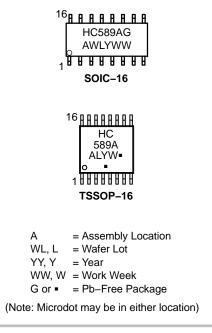
http://onsemi.com



PIN ASSIGNMENT

| В | 1• | 16 | V _{cc} |
|-------|----|----|--------------------------------|
| С | 2 | 15 |] A |
| D | 3 | 14 |] S _A |
| ΕC | 4 | 13 | SERIAL SHIFT/ PARALLEL LOAD |
| F | 5 | 12 |] LATCH CLOCK |
| G | 6 | 11 |] SHIFT CLOCK |
| н[| 7 | 10 | OUTPUT ENABLE |
| GND [| 8 | 9 | l QH |
| | | | |

MARKING DIAGRAMS



ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 10 of this data sheet.

MAXIMUM RATINGS

| Symbol | F | Value | Unit | |
|----------------------|---|--|---------------------------|------|
| V _{CC} | DC Supply Voltage | (Referenced to GND) | -0.5 to +7.0 | V |
| V _{in} | DC Input Voltage | (Referenced to GND) | $-0.5 \leq V_{CC} + 0.5$ | V |
| V _{out} | DC Output Voltage | (Referenced to GND) | $-0.5 \leq V_{CC} + 0.5$ | V |
| I _{in} | DC Input Current, per Pin | | ±20 | mA |
| I _{out} | DC Output Current, per Pin | | ±35 | mA |
| I _{CC} | DC Supply Current, V_{CC} and GND Pir | ns | ±75 | mA |
| I _{GND} | DC Ground Current per Ground Pin | | ±75 | mA |
| T _{STG} | Storage Temperature Range | | -65 to +150 | °C |
| ΤL | Lead Temperature, 1 mm from Case for | or 10 Seconds | 260 | °C |
| ΤJ | Junction Temperature Under Bias | | +150 | °C |
| θ_{JA} | Thermal Resistance | PDIP SOIC TSSOP | 78 112 148 | °C/W |
| P _D | Power Dissipation in Still Air at 85°C | PDIP SOIC TSSOP | 750 500 450 | mW |
| MSL | Moisture Sensitivity | | Level 1 | |
| F _R | Flammability Rating | Oxygen Index: 30% – 35% | UL 94 V–0 @ 0.125 in | |
| V _{ESD} | ESD Withstand Voltage | Human Body Model (Note 1) Machine Model (Note 2) Charged Device Model (Note 3) | > 4000 > 200 > 1000 | V |
| I _{Latchup} | Latchup Performance | Above V _{CC} and Below GND at 85° C (Note 4) | ±300 | mA |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

Tested to EIA/JESD22–A114–A.
Tested to EIA/JESD22–A115–A.

3. Tested to JESD22-C101-A.

4. Tested to EIA/JESD78.

RECOMMENDED OPERATING CONDITIONS

| Symbol | Parameter | Min | Max | Unit | |
|------------------------------------|--|--|-------------|---------------------------|----|
| V _{CC} | DC Supply Voltage | (Referenced to GND) | 2.0 | 6.0 | V |
| V _{in} , V _{out} | DC Input Voltage, Output Voltage | (Referenced to GND) | 0 | V _{CC} | V |
| T _A | Operating Temperature, All Package Types | | -55 | + 125 | °C |
| t _r , t _f | Input Rise and Fall Time (Figure 2) | $V_{CC} = 2.0 V$ $V_{CC} = 3.0 V$ $V_{CC} = 4.5 V$ $V_{CC} = 6.0 V$ | 0 0 0 | 1000 800 500 400 | ns |

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability. 5. Unused inputs may not be left open. All inputs must be tied to a high–logic voltage level or a low–logic input voltage level.

| | | | | Guaranteed Limit | | | |
|-----------------|--|--|--------------------------|---------------------------|---------------------------|---------------------------|------|
| Symbol | Parameter | Test Conditions | v | –55°C to 25°C | ≤ 85°C | ≤ 125°C | Unit |
| V _{IH} | Minimum High-Level Input Voltage | $\begin{array}{l} V_{out} = 0.1 \text{ V or } V_{CC} - 0.1 \text{ V} \\ I_{out} \leq 20 \ \mu\text{A} \end{array}$ | 2.0 3.0 4.5 6.0 | 1.5 2.1 3.15 4.2 | 1.5 2.1 3.15 4.2 | 1.5 2.1 3.15 4.2 | V |
| V _{IL} | Maximum Low–Level Input Voltage | $\label{eq:Vout} \begin{array}{l} V_{out} = 0.1 \ V \ or \ V_{CC} \ -0.1 \ V \\ I_{out} \leq 20 \ \mu A \end{array}$ | 2.0 3.0 4.5 6.0 | 0.5 0.9 1.35 1.8 | 0.5 0.9 1.35 1.8 | 0.5 0.9 1.35 1.8 | V |
| V _{OH} | Minimum High–Level Output Voltage | | 2.0 4.5 6.0 | 1.9 4.4 5.9 | 1.9 4.4 5.9 | 1.9 4.4 5.9 | V |
| | | $\label{eq:Vin} \begin{array}{ll} V_{in} = V_{IH} \text{ or } V_{IL} & \qquad I_{out} \leq 2.4 \text{ mA} \\ I_{out} \leq 6.0 \text{ mA} \\ I_{out} \leq 7.8 \text{ mA} \end{array}$ | 3.0 4.5 6.0 | 2.48 3.98 5.48 | 2.34 3.84 5.34 | 2.20 3.70 5.20 | |
| V _{OL} | Maximum Low–Level Output Voltage | $V_{in} = V_{IH}$ $ I_{out} \le 20 \ \mu A$ | 2.0 4.5 6.0 | 0.1 0.1 0.1 | 0.1 0.1 0.1 | 0.1 0.1 0.1 | V |
| | | $\label{eq:Vin} \begin{array}{ll} V_{in} = V_{IH} \text{ or } V_{IL} & \qquad I_{out} \leq 2.4 \text{ mA} \\ I_{out} \leq 6.0 \text{ mA} \\ I_{out} \leq 7.8 \text{ mA} \end{array}$ | 3.0 4.5 6.0 | 0.26 0.26 0.26 | 0.33 0.33 0.33 | 0.40 0.40 0.40 | |
| I _{in} | Maximum Input Leakage Current | $V_{in} = V_{CC}$ or GND | 6.0 | ±0.1 | ±1.0 | ±1.0 | μΑ |
| I _{OZ} | Maximum Three–State Leakage Current | Output in High–Impedance State $V_{in} = V_{IL} \text{ or } V_{IH}$ $V_{out} = V_{CC} \text{ or GND}$ | 6.0 | ±0.5 | ±5.0 | ±10 | μΑ |
| Icc | Maximum Quiescent Supply Current (per Package) | V _{in} = V _{CC} or GND I _{out} = 0 μA | 6.0 | 4 | 40 | 160 | μΑ |

DC ELECTRICAL CHARACTERISTICS (Voltages Referenced to GND)

| | | V _{CC} | Guaranteed Limit | | | |
|--|--|--------------------------|------------------------|---------------------------------------|------------------------|------|
| Symbol | Parameter | v | –55°C to 25°C | 55°C to 25°C \leq 85°C \leq 125°C | | Unit |
| f _{max} | Maximum Clock Frequency (50% Duty Cycle) (Figures 3 and9) | 2.0 3.0 4.5 6.0 | 6.0 15 30 35 | 4.8 10 24 28 | 4.0 8.0 20 24 | MHz |
| t _{PLH} , t _{PHL} | Maximum Propagation Delay, Latch Clock to Q _H (Figures 2 and 9) | 2.0 3.0 4.5 6.0 | 175 100 40 30 | 225 110 50 40 | 275 125 60 50 | ns |
| t _{PLH} , t _{PHL} | Maximum Propagation Delay, Shift Clock to Q _H (Figures 3 and 9) | 2.0 3.0 4.5 6.0 | 160 90 30 25 | 200 130 40 30 | 240 160 48 40 | ns |
| t _{PLH} , t _{PHL} | Maximum Propagation Delay, Serial Shift/Parallel Load to Q _H (Figures 5 and 9) | 2.0 3.0 4.5 6.0 | 160 90 30 25 | 200 130 40 30 | 240 160 48 40 | ns |
| t _{PLZ} , t _{PHZ} | Maximum Propagation Delay, Output Enable to Q _H (Figures 4 and 10) | 2.0 3.0 4.5 6.0 | 150 80 27 23 | 170 100 30 25 | 200 130 40 30 | ns |
| t _{PZL} , t _{PZH} | Maximum Propagation Delay, Output Enable to Q _H (Figures 4 and 10) | 2.0 3.0 4.5 6.0 | 150 80 27 23 | 170 100 30 25 | 200 130 40 30 | ns |
| t _{TLH} , t _{THL} | Maximum Output Transition Time, Any Output (Figures 2 and 9) | 2.0 3.0 4.5 6.0 | 60 23 12 10 | 75 27 15 13 | 90 31 18 15 | ns |
| C _{in} | Maximum Input Capacitance | - | 10 | 10 | 10 | pF |
| C _{out} | Maximum Three–State Output Capacitance (Output in High–Impedance State) | - | 15 | 15 | 15 | pF |

AC ELECTRICAL CHARACTERISTICS ($C_L = 50 \text{ pF}$, Input $t_r = t_f = 6 \text{ ns}$)

| | | Typical @ 25°C, V _{CC} = 5.0 V | |
|-----------------|--|---|----|
| C _{PD} | Power Dissipation Capacitance (per Package)* | 50 | pF |

*Used to determine the no–load dynamic power consumption: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

TIMING REQUIREMENTS (Input t_r = t_f = 6 ns)

| | | V _{CC} | Guarar | nteed Limi | t | |
|---------------------------------|---|--------------------------|---------------------------|---------------------------|---------------------------|------|
| Symbol | Parameter | v | –55°C to 25°C | ≤ 85°C | ≤ 125°C | Unit |
| t _{su} | Minimum Setup Time, A–H to Latch Clock (Figure 6) | 2.0 3.0 4.5 6.0 | 100 40 20 17 | 125 50 25 21 | 150 60 30 26 | ns |
| t _{su} | Minimum Setup Time, Serial Data Input S _A to Shift Clock (Figure 7) | 2.0 3.0 4.5 6.0 | 100 40 20 17 | 125 50 25 21 | 150 60 30 26 | ns |
| t _{su} | Minimum Setup Time, Serial Shift/Parallel Load to Shift Clock (Figure 8) | 2.0 3.0 4.5 6.0 | 100 40 20 17 | 125 50 25 21 | 150 60 30 26 | ns |
| t _h | Minimum Hold Time, Latch Clock to A–H (Figure 6) | 2.0 3.0 4.5 6.0 | 25 10 5 5 | 30 12 6 6 | 40 15 8 7 | ns |
| t _h | Minimum Hold Time, Shift Clock to Serial Data Input S _A (Figure 7) | 2.0 3.0 4.5 6.0 | 5 5 5 5 | 5 5 5 5 | 5 5 5 5 | ns |
| t _w | Minimum Pulse Width, Shift Clock (Figure 3) | 2.0 3.0 4.5 6.0 | 75 40 15 13 | 95 50 19 16 | 110 60 23 19 | ns |
| t _w | Minimum Pulse Width, Latch Clock (Figure 2) | 2.0 3.0 4.5 6.0 | 80 40 16 14 | 100 50 20 17 | 120 60 24 20 | ns |
| t _w | Minimum Pulse Width, Serial Shift/Parallel Load (Figure 5) | 2.0 3.0 4.5 6.0 | 80 40 16 14 | 100 50 20 17 | 120 60 24 20 | ns |
| t _r , t _f | Maximum Input Rise and Fall Times (Figure 2) | 2.0 3.0 4.5 6.0 | 1000 800 500 400 | 1000 800 500 400 | 1000 800 500 400 | ns |

FUNCTION TABLE

| | | | Input | S | | | F | Resulting Funct | ion |
|--|------------------|--------------------------------|----------------|----------------|-----------------------------------|---------------------------|---------------------------|---|---|
| Operation | Output Enable | Serial Shift/ Parallel Load | Latch Clock | Shift Clock | Serial Input S _A | Parallel Inputs A–H | Data Latch Contents | Shift Register Contents | Output Q _H |
| Force Output into High Impedance State | Н | х | х | Х | Х | Х | Х | х | Z |
| Load Parallel Data into Data Latch | L | Н | ~ | L, H, ~ | Х | a–h | a–h | U | U |
| Transfer Latch Contents to Shift Register | L | L | L, H, 🔨 | Х | Х | Х | U | $LR_N \mathop{\rightarrow} SR_N$ | LR _H |
| Contents of Input Latch and Shift Register are Unchanged | L | Н | L, H, 🔨 | L, H, 🔨 | Х | Х | U | U | U |
| Load Parallel Data into Data Latch and Shift Register | L | L | 7 | Х | Х | a–h | a-h | a–h | h |
| Shift Serial Data into Shift Register | L | Н | Х | 7 | D | Х | * | $\begin{array}{l} SR_A = D, \\ SR_N \rightarrow SR_{N+1} \end{array}$ | $\text{SR}_G {\rightarrow} \text{SR}_H$ |
| Load Parallel Data in Data Latch and Shift Serial Data into Shift Register | L | Н | | ـر | D | a-h | a-h | $\begin{array}{l} SR_{A} = D, \\ SR_{N} \rightarrow SR_{N+1} \end{array}$ | $SR_G \to SR_H$ |

LR = latch register contents

SR = shift register contents

a-h = data at parallel data inputs A-H

D = data (L, H) at serial data input S_A

U = remains unchanged

X = don't care

Z = high impedance

* = depends on Latch Clock input

SWITCHING WAVEFORMS

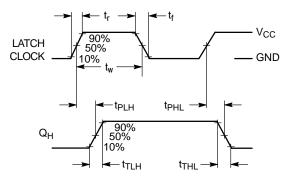


Figure 2. (Serial Shift/Parallel Load = L)

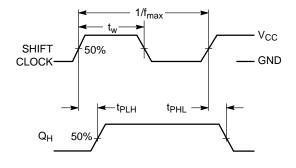
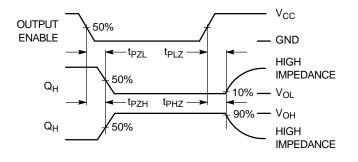
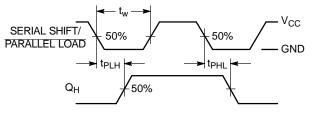


Figure 3. (Serial Shift/Parallel Load = H)

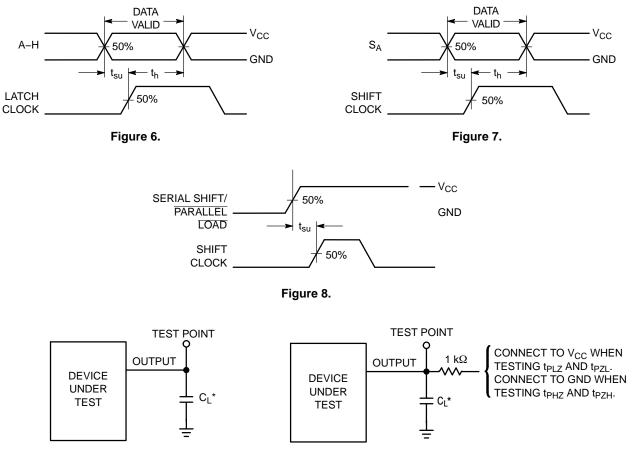








SWITCHING WAVEFORMS



*Includes all probe and jig capacitance.

Figure 9. Test Circuit

*Includes all probe and jig capacitance.

Figure 10. Test Circuit

PIN DESCRIPTIONS

Data Inputs

A, B, C, D, E, F, G, H (Pins 15, 1, 2, 3, 4, 5, 6, 7)

Parallel data inputs. Data on these inputs are stored in the data latch on the rising edge of the Latch Clock input.

S_A (Pin 14)

Serial data input. Data on this input is shifted into the shift register on the rising edge of the Shift Clock input if Serial Shift/Parallel Load is high. Data on this input is ignored when Serial Shift/Parallel Load is low.

Control Inputs

Serial Shift/Parallel Load (Pin 13)

Shift register mode control. When a high level is applied to this pin, the shift register is allowed to serially shift data. When a low level is applied to this pin, the shift register accepts parallel data from the data latch.

Shift Clock (Pin 11)

Serial shift clock. A low-to-high transition on this input shifts data on the serial data input into the shift register and

data in stage H is shifted out Q_H , being replaced by the data previously stored in stage G.

Latch Clock (Pin 12)

Data latch clock. A low-to-high transition on this input loads the parallel data on inputs A–H into the data latch.

Output Enable (Pin 10)

Active–low output enable A high level applied to this pin forces the Q_H output into the high impedance state. A low level enables the output. This control does not affect the state of the input latch or the shift register.

Output

Q_H (Pin 9)

Serial data output. This pin is the output from the last stage of the shift register. This is a 3–state output.

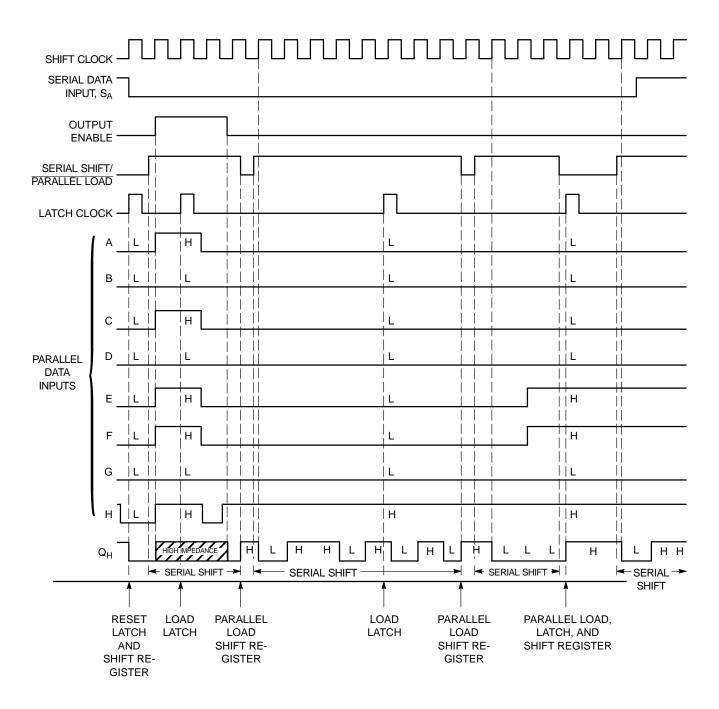
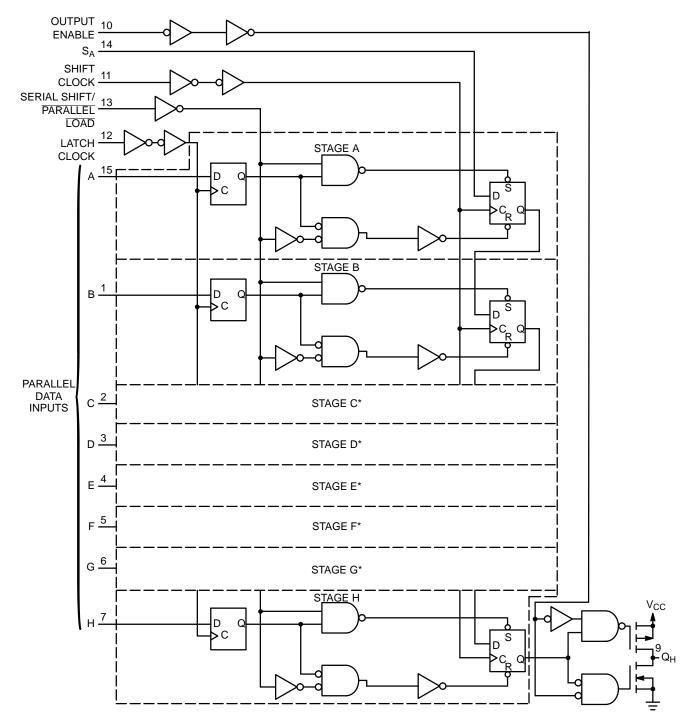


Figure 11. Timing Diagram



*Stages C thru G (not shown in detail) are identical to stages A and B above.

Figure 12. Logic Detail

ORDERING INFORMATION

| Device | Package | Shipping [†] |
|-------------------|-----------------------|-----------------------|
| MC74HC589ADG | SOIC-16 (Pb-Free) | 48 Units / Rail |
| NLV74HC589ADG* | SOIC-16 (Pb-Free) | 48 Units / Rail |
| MC74HC589ADR2G | SOIC-16 (Pb-Free) | 2500 Tape & Reel |
| NLV74HC589ADR2G* | SOIC-16 (Pb-Free) | 2500 Tape & Reel |
| MC74HC589ADTR2G | TSSOP-16 (Pb-Free) | 2500 Tape & Reel |
| NLV74HC589ADTR2G* | TSSOP-16 (Pb-Free) | 2500 Tape & Reel |

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

*NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q100 Qualified and PPAP Capable.





DIMENSIONS: MILLIMETERS

| DOCUMENT NUMBER: | 98ASB42566B | Electronic versions are uncontrolled except when accessed directly from the Document Repositor Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red. | | | |
|---|-------------|---|-------------|--|--|
| DESCRIPTION: | SOIC-16 | | PAGE 1 OF 1 | | |
| ON Semiconductor and 👊 are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding | | | | | |

ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the rights of others.





| DOCUMENT NUMBER: | 98ASH70247A | Electronic versions are uncontrolled except when accessed directly from the Document Repos Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red. | | | |
|--|-------------|---|-------------|--|--|
| DESCRIPTION: | TSSOP-16 | - | PAGE 1 OF 1 | | |
| ON Semiconductor and up are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. | | | | | |

ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the rights of others.

ON Semiconductor and are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at <u>www.onsemi.com/site/pdf/Patent-Marking.pdf</u>. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor date sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights nor the rights of others. ON Semiconductor products are not designed, intended, or authorized for use a a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor houteds for any such unintended or unauthorized application, Buyer shall indemnify and hold ON Semiconductor and its officers, employees, subsidiaries

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

TECHNICAL SUPPORT

ON Semiconductor Website: www.onsemi.com

Email Requests to: orderlit@onsemi.com

North American Technical Support: Voice Mail: 1 800–282–9855 Toll Free USA/Canada Phone: 011 421 33 790 2910 Europe, Middle East and Africa Technical Support: Phone: 00421 33 790 2910 For additional information, please contact your local Sales Representative